

# **N-Channel MOSFET Transistor**

## **FEATURES**

- · Drain Current -I<sub>D</sub>= 47A@ T<sub>C</sub>=25℃
- · Drain Source Voltage -V<sub>DSS</sub>= 600V(Min)
- · Static Drain-Source On-Resistance
- $-R_{DS(on)} = 0.07\Omega(Max)@V_{GS} = 10V$

## **APPLICATIONS**

- · DC-DC Converters
- · Automatic Test Equipment
- · High-Side Switching



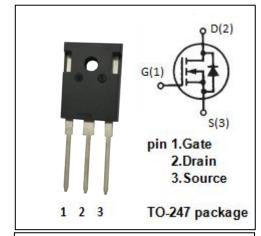
# Absolute Maximum Ratings(T<sub>C</sub>=25℃)

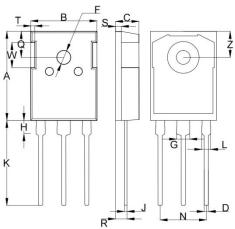
SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
I <sub>D</sub>	Drain Current-Continuous	47	А
I <sub>DM</sub>	Drain Current-Single Pulse	141	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	417	W
TJ	Max. Operating Junction Temperature 150		$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.3	°C/W	

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DIM	mm			
	MIN	TYP.	MAX	
Α	19.80	20.65	21.50	
В	15.40	15.65	15.90	
С	4.70	5.00	5.30	
D	0.90	1.08	1.26	
F	3.50	3.70	3.90	
G	2.70	3.00	3.30	
Н	3.90	4.05	4.20	
J	0.50	0.60	0.70	
K	19.50	20.00	20.50	
L	1.90	2.05	2.20	
N	10.80	10.90	11.00	
Q	6.00	6.15	6.30	
R	2.90	3.10	3.30	
S	1.80	2.00	2.20	
T	2.15	2.25	2.35	
W	4.90	5.00	5.10	
Z	6.00	6.15	6.30	



# ISF1182 ea APT47N60BC3G

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#### **ELECTRICAL CHARACTERISTICS (Tc=25°C)**

	TELOTRICAL OFFICE (IC 200)						
SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT	
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0, I <sub>D</sub> = 0.25mA	600	-	-	V	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 600V, V <sub>GS</sub> = 0V	-	-	25	uA	
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V,V <sub>DS</sub> = 0 V	-	-	±100	nA	
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 2.7mA	2.5	-	4.5	V	
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A	-	-	0.07	Ω	
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 47A, V <sub>GS</sub> = 0V	-	-	1.2	V	

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